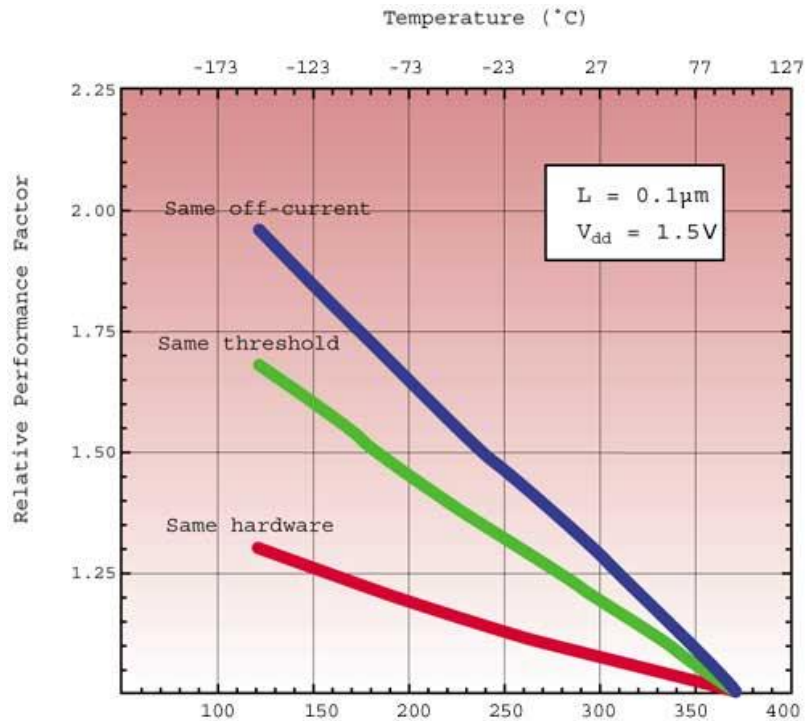


Implications of Full-System Modeling for Superconducting Architectures

Kunal Pai, Mahyar Samani, Anusheel Nand & Jason Lowe-Power

Introduction



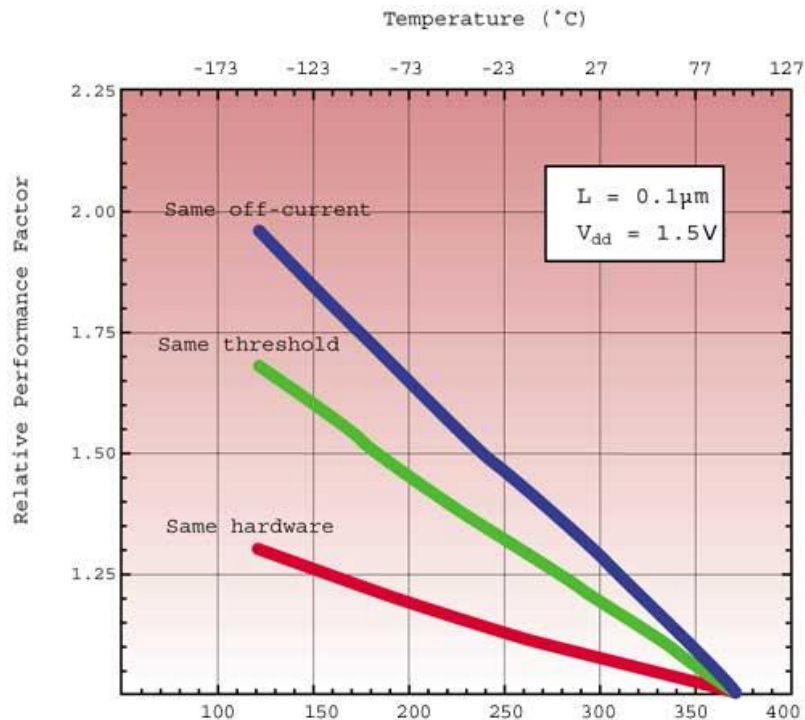
source: <https://www.electronics-cooling.com/2001/08/the-challenge-of-operating-computers-at-ultra-low-temperatures/>

CMOS -> high leakage currents,
reduced perf. at high temp

CryoCMOS and superconductors ->
low temp., high perf., high energy efficiency



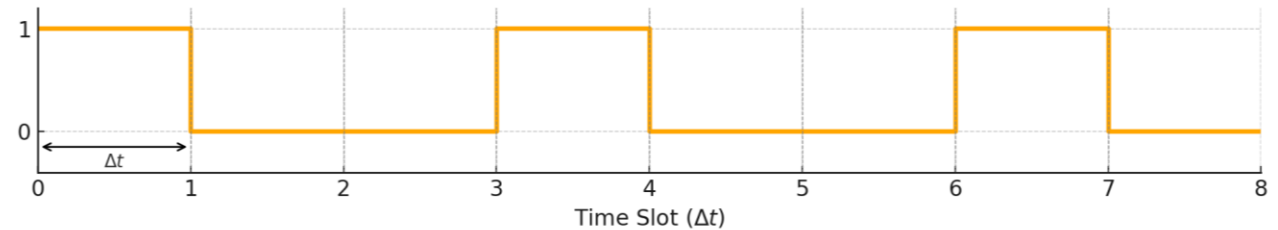
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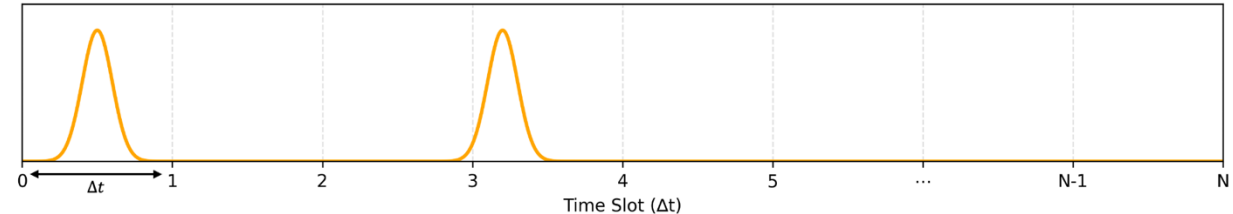
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Cryogenic CMOS: 123 K, 4 GHz clk.

- Same logic as regular CMOS



Superconducting electronics: 10 K, max. 100 GHz clk.

- Logic based on detection of pulse at time steps (race logic)

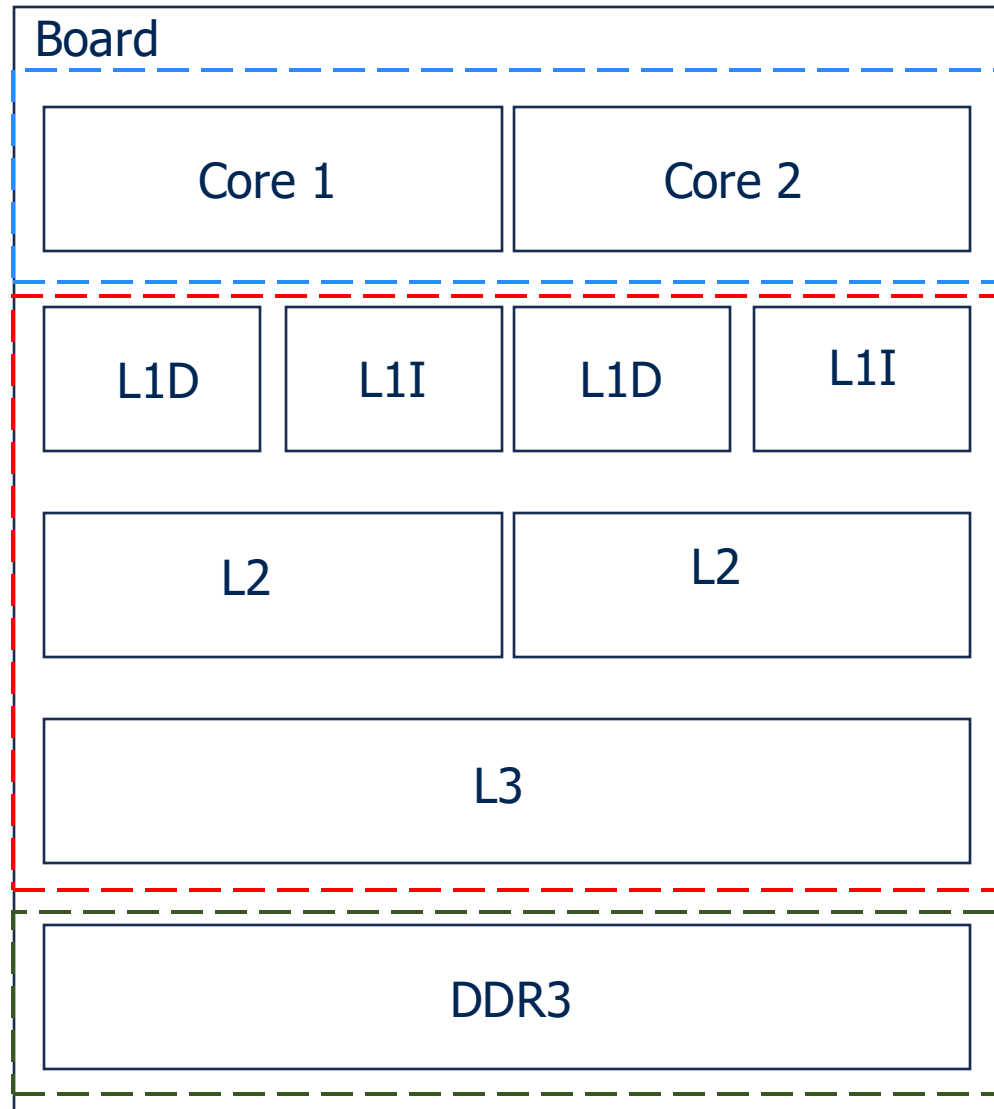


Contributions

- ***First*** full-system study on CryoCMOS & Superconductors
 - gem5: cycle-level simulator @ v23.1
 - Diverse workloads: SPEC CPU2006 (ref), BFS, PR, CC
 - Theoretical and realistic architectures



Theoretical Super- & Cryo- Architecture Modeling



Cryo (4 GHz) /
Super (100 GHz)

OOO (BOOM) /
In-order (HiFive Unmatched)

Cryo (4 GHz) /
Super (100 GHz)

L1 32 kB, L2 512 kB, L3 16 MB

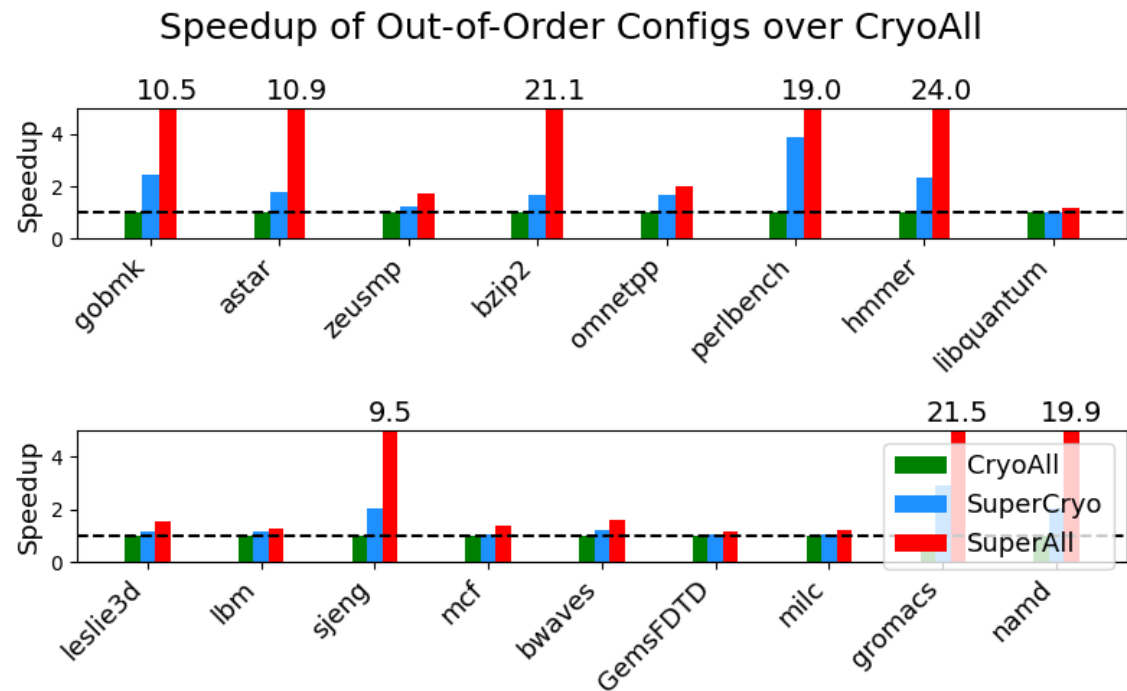
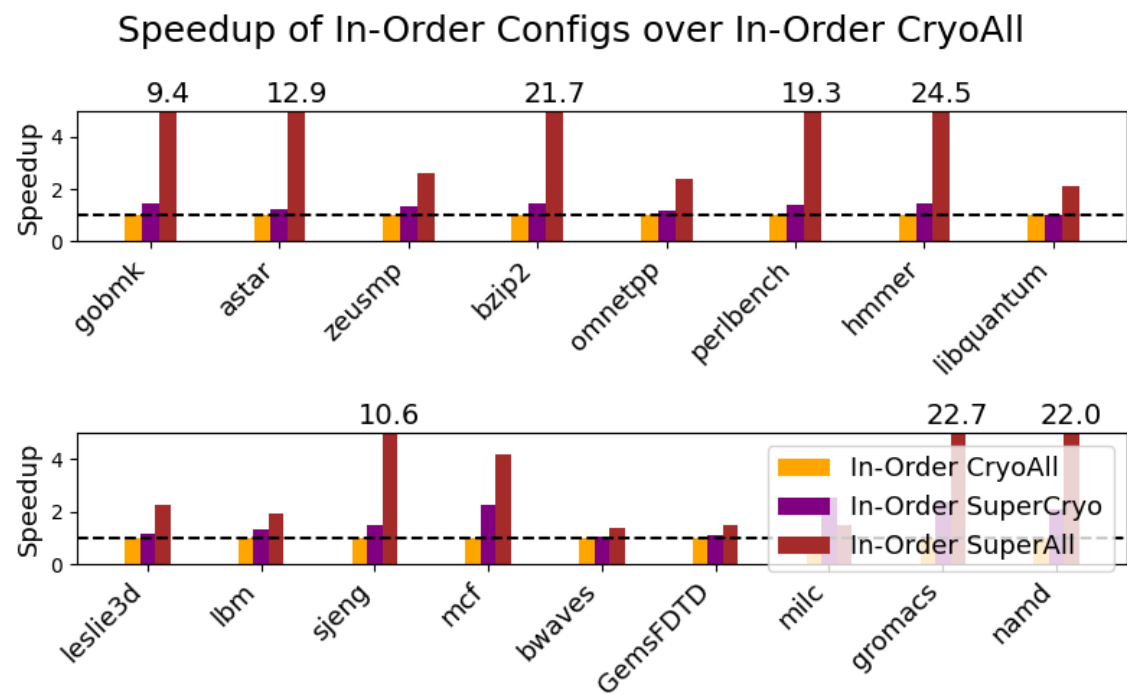
Room temp. (800 MHz)

Mem. hard to scale in cryo/super



Performance Improvement

- High potential bar:
 - but low freq. caches are bottleneck
- More abs. impact on in-order
 - Latency hiding less important
- Memory-intensive workloads:
 - minimal improvement
- Main bottleneck:
 - Room temp. DRAM



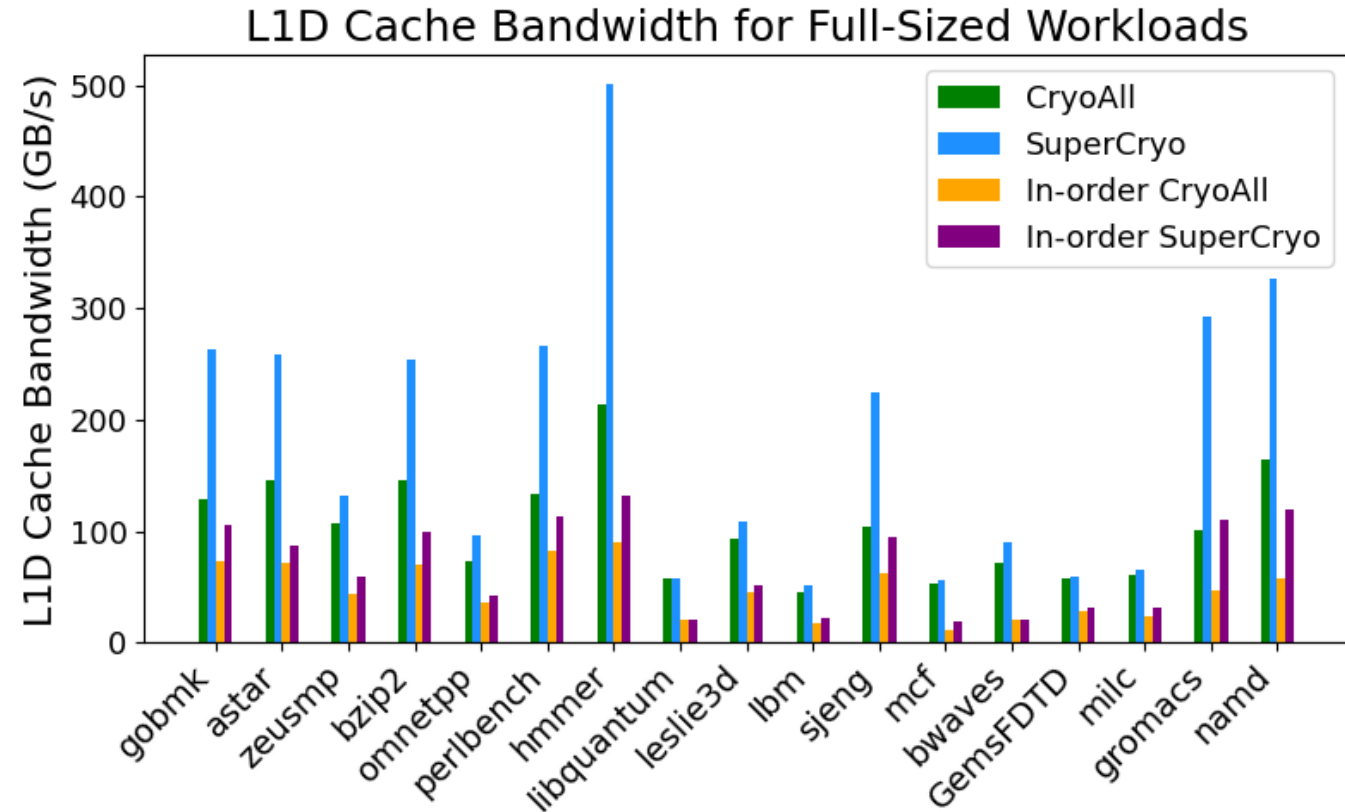
Performance Improvement

- Take away:
 - Big potential benefits, but only for some workloads: **Accelerator, Interconnect**



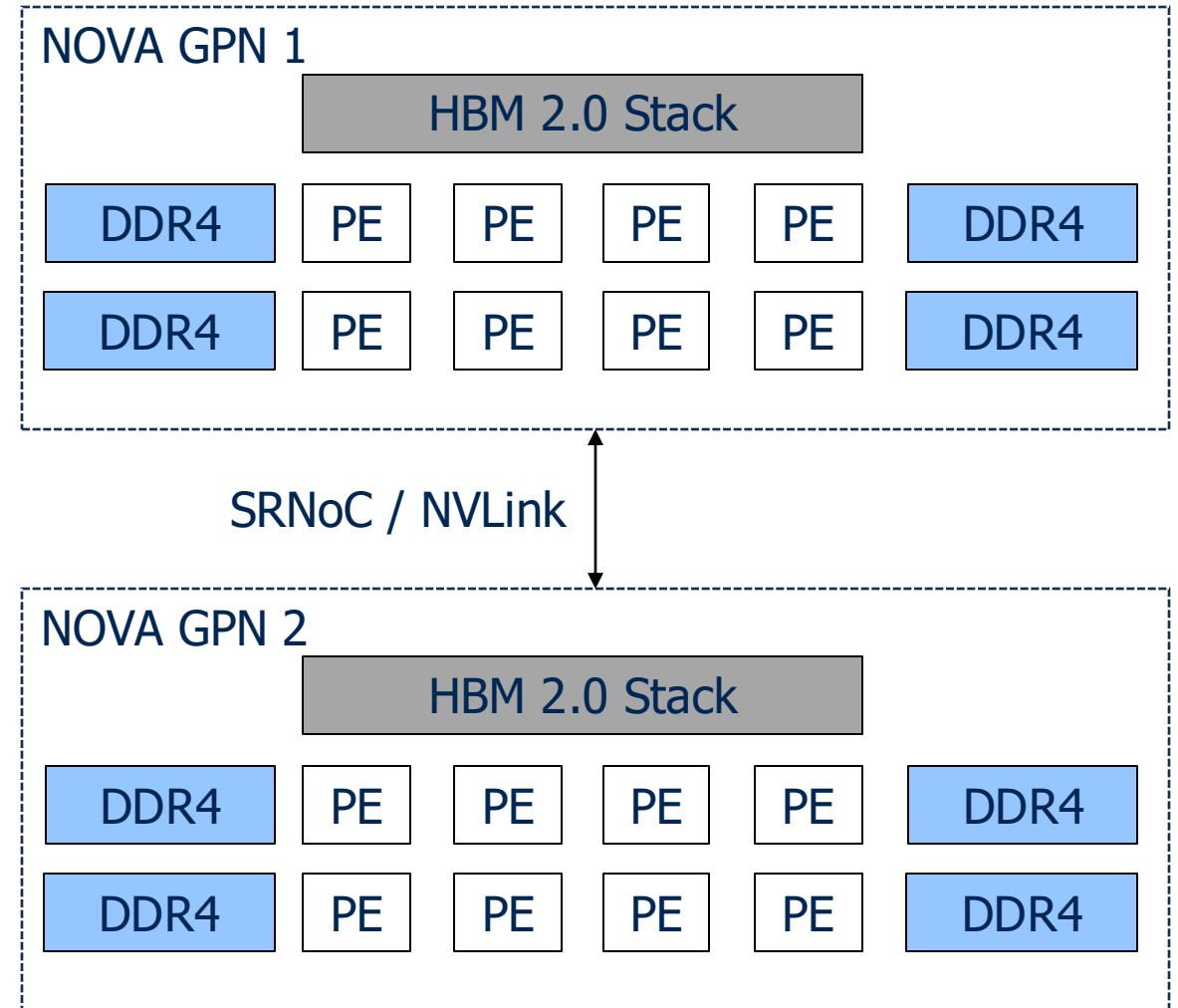
Data Movement

- CryoAll and SuperCryo (in-order and OOO) - realistic configs
- Max. 500 GB/s for L1D Cache in SuperCryo configuration.
 - Reasonable for optics!



Interconnect Model

- SRNoC: Circuit-switched, statically-scheduled
- Workloads: BFS, PR and CC
- Graph size: 12 k nodes, 60 k edges



SRNoC Results

Workload	Slowdown	NVLink Energy (J)	SRNoC Energy (J)	Efficiency Gain
BFS	1.05×	1.06×10^{-6}	2.95×10^{-8}	35.98×
CC	1.31×	1.31×10^{-4}	1.78×10^{-6}	73.60×
PR	1246.28×	2.32×10^{-6}	6.44×10^{-5}	0.04×

- All workloads: **slowdown**
- Narrow int data paths (8-bit): BFS and CC - **low** slowdown, **high** energy efficiency
- Float transmissions (32-bit): PR - **high** slowdown, **low** energy efficiency



Conclusion

- **Compute-intensive workloads**: gains as high as 24x
 - Limited by CMOS DRAM
- **General-purpose CPUs**: limited benefit
- **Best use case**: narrow-path, domain-specific accelerators (graph / ML)
- **Future**: Explore superconducting memory and SERDES conversion penalties

